

ULTRALOW QUIESCENT CURRENT 250-mA LOW DROPOUT VOLTAGE REGULATORS

FEATURES

- 250-mA Low Dropout Voltage Regulator
- Available in 1.5 V, 1.8 V, 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V, 5.0 V Fixed Output and Adjustable Versions
- Dropout Voltage to 140 mV (Typ) at 250 mA (TPS76650)
- Ultralow 35- μ A Typical Quiescent Current
- 3% Tolerance Over Specified Conditions for Fixed Output Versions
- Open-Drain Power Good
- 8-Pin SOIC Package
- Thermal Shutdown Protection

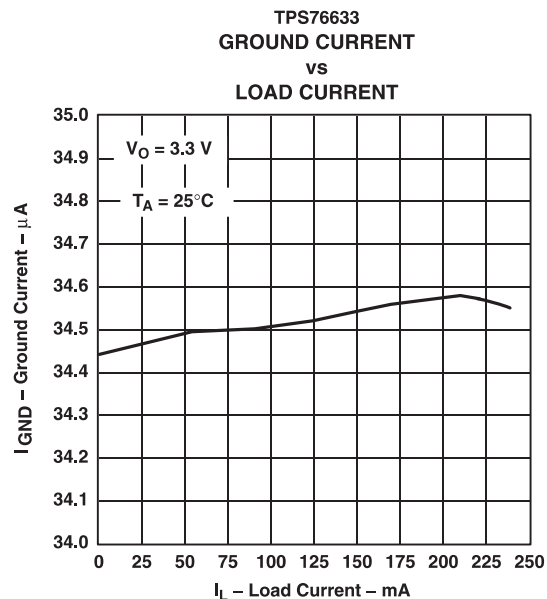
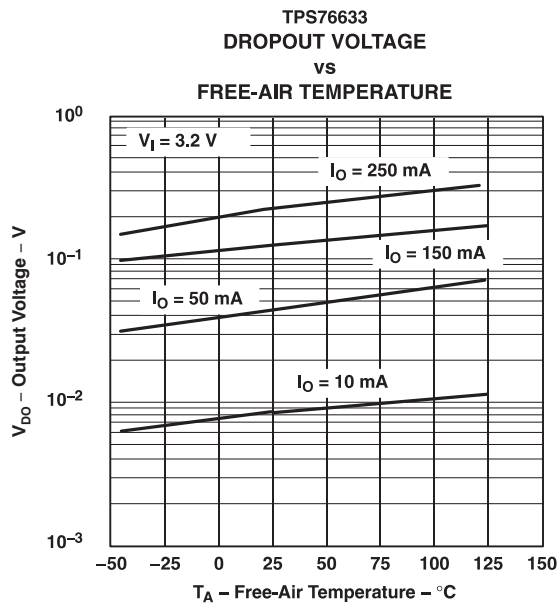
DESCRIPTION

This device is designed to have an ultralow quiescent current and be stable with a 4.7- μ F capacitor. This combination provides high performance at a reasonable cost.

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 230 mV at an output current of 250 mA for the TPS76650) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 35 μ A over the full range of output current, 0 mA to 250 mA). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO family also features a sleep mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to less than 1 μ A (typ).

Power good (PG) is an active high output that can be used to implement a power-on reset or a low-battery indicator.

The TPS766xx is offered in 1.5 V, 1.8 V, 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V and 5.0 V fixed voltage versions and in an adjustable version (programmable over the range of 1.25 V to 5.5 V). Output voltage tolerance is specified as a maximum of 3% over line, load, and temperature ranges. The TPS766xx family is available in an 8-pin SOIC package.



TPS76615, TPS76618, TPS76625
TPS76627, TPS76628, TPS76630
TPS76633, TPS76650, TPS76601



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
TPS766xyz	XX is nominal output voltage (for example, 28 = 2.8V, 01 = Adjustable). ⁽³⁾ Y is package designator. Z is package quantity.

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Output voltages from 1.5 V to 5.0 V in 50-mV increments are available through the use of innovative factory EEPROM programming; minimum order quantities may apply. Contact factory for details and availability.
- (3) The TPS76601 is programmable using an external resistor divider (see [Application Information](#)).

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range (unless otherwise noted).⁽¹⁾

PARAMETER	TPS766xx	UNIT
V _I Input voltage range ⁽²⁾	−0.3 to 13.5	V
Voltage range at \overline{EN}	−0.3 to 16.5	V
Maximum PG voltage	16.5	V
Peak output current	Internally limited	
Continuous total power dissipation	See Dissipation Ratings Table	
V _O Output voltage (OUT, FB)	7	V
T _J Operating virtual junction temperature range	−40 to +125	°C
T _{stg} Storage temperature range	−65 to +150	°C
ESD rating, HBM	2	kV

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) All voltage values are with respect to network terminal ground.

DISSIPATION RATINGS

PACKAGE	AIR FLOW (CFM)	T _A < +25°C POWER RATING	DERATING FACTOR ABOVE T _A = +25°C	T _A = +70°C POWER RATING	T _A = +85°C POWER RATING
D	0	568 mW	5.68 mW/°C	312 mW	227 mW
	250	904 mW	9.04 mW/°C	497 mW	361 mW

RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
V _I Input voltage ⁽¹⁾	2.7	10	V
V _O Output voltage range	1.2	5.5	V
I _O Output current ⁽²⁾	0	250	mA
T _J Operating virtual junction temperature ⁽²⁾	−40	125	°C

- (1) To calculate the minimum input voltage for your maximum output current, use the following equation: $V_{I(min)} = V_{O(max)} + V_{DO(max\ load)}$
- (2) Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

ELECTRICAL CHARACTERISTICS

Over recommended operating free-air temperature range, $V_I = V_{O(typ)} + 1\text{ V}$, $I_O = 10\text{ }\mu\text{A}$, $\overline{\text{EN}} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output voltage (10 μA to 250 mA load) ⁽¹⁾	TPS76601	5.5 V ≥ V _O ≥ 1.25 V,	T _J = +25°C		V _O		V
		5.5 V ≥ V _O ≥ 1.25 V,	T _J = −40°C to +125°C	0.97 V _O		1.03 V _O	
	TPS76615	T _J = +25°C,	2.7 V < V _{IN} < 10 V		1.5		
		T _J = −40°C to +125°C,	2.7 V < V _{IN} < 10 V	1.455		1.545	
	TPS76618	T _J = +25°C,	2.8 V < V _{IN} < 10 V		1.8		
		T _J = −40°C to +125°C,	2.8 V < V _{IN} < 10 V	1.746		1.854	
	TPS76625	T _J = +25°C,	3.5 V < V _{IN} < 10 V		2.5		
		T _J = −40°C to +125°C,	3.5 V < V _{IN} < 10 V	2.425		2.575	
	TPS76627	T _J = +25°C,	3.7 V < V _{IN} < 10 V		2.7		
		T _J = −40°C to +125°C,	3.7 V < V _{IN} < 10 V	2.619		2.781	
	TPS76628	T _J = +25°C,	3.8 V < V _{IN} < 10 V		2.8		
		T _J = −40°C to +125°C,	3.8 V < V _{IN} < 10 V	2.716		2.884	
	TPS76630	T _J = +25°C,	4.0 V < V _{IN} < 10 V		3.0		
		T _J = −40°C to +125°C,	4.0 V < V _{IN} < 10 V	2.910		3.090	
	TPS76633	T _J = +25°C,	4.3 V < V _{IN} < 10 V		3.3		
		T _J = −40°C to +125°C,	4.3 V < V _{IN} < 10 V	3.201		3.399	
	TPS76650	T _J = +25°C,	6.0 V < V _{IN} < 10 V		5.0		
		T _J = −40°C to +125°C,	6.0 V < V _{IN} < 10 V	4.850		5.150	
Quiescent current (GND current) $\overline{\text{EN}}$ = 0 V ⁽¹⁾		10 μA < I _O < 250 mA,	T _J = +25°C		35		μA
		I _O = 250 mA,	T _J = −40°C to +125°C			50	
Output voltage line regulation (ΔV _O /V _O) ^{(1),(2)}		V _O + 1 V < V _I ≤ 10 V,	T _J = +25°C		0.01		%/V
Load regulation		I _O = 10 μA to 250 mA			0.5%		
Output noise voltage		BW = 300 Hz to 50 kHz, C _O = 4.7 μF, T _J = +25°C			200		μVrms
Output current limit		V _O = 0 V			0.8	1.2	A
Thermal shutdown junction temperature					150		°C
Standby current		$\overline{\text{EN}}$ = V _I ,	T _J = +25°C 2.7 V < V _I < 10 V		1		μA
		$\overline{\text{EN}}$ = V _I ,	T _J = −40°C to +125°C 2.7 V < V _I < 10 V			10	μA
FB input current	TPS76601	FB = 1.5 V			2		nA
High level enable input voltage					2.0		V
Low level enable input voltage						0.8	V
Power-supply ripple rejection ⁽¹⁾		f = 1 kHz, I _O = 10 μA,	C _O = 4.7 μF, T _J = +25°C		63		dB

(1) Minimum IN operating voltage is 2.7 V or $V_{O(typ)} + 1\text{ V}$, whichever is greater. Maximum IN voltage 10 V.

(2) If $V_O \geq 1.8\text{ V}$ then $V_{imin} = 2.7\text{ V}$, $V_{imax} = 10\text{ V}$:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O(V_{imax} - 2.7\text{ V})}{100} \times 1000$$

If $V_O \leq 2.5\text{ V}$ then $V_{imin} = V_O + 1\text{ V}$, $V_{imax} = 10\text{ V}$:

$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O(V_{imax} - (V_O + 1\text{ V}))}{100} \times 1000$$

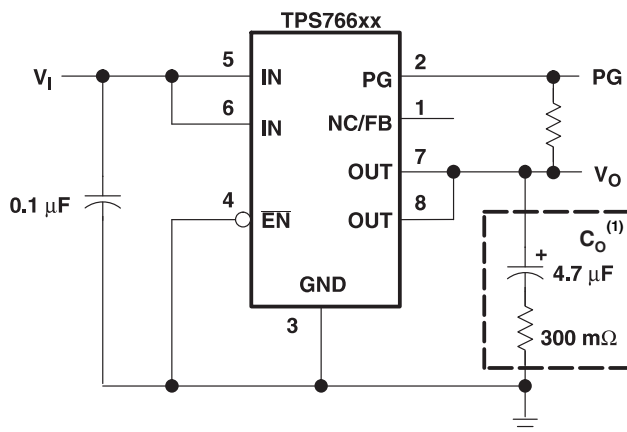
**TPS76615, TPS76618, TPS76625
TPS76627, TPS76628, TPS76630
TPS76633, TPS76650, TPS76601**

ELECTRICAL CHARACTERISTICS (continued)

Over recommended operating free-air temperature range, $V_I = V_{O(\text{typ})} + 1 \text{ V}$, $I_O = 10 \mu\text{A}$, $\overline{\text{EN}} = 0 \text{ V}$, $C_O = 4.7 \mu\text{F}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
PG	Minimum input voltage for valid PG	$I_{O(\text{PG})} = 300 \mu\text{A}$		1.1		
	Trip threshold voltage	V_O decreasing	92		98	% V_O
	Hysteresis voltage	Measured at V_O		0.5		% V_O
	Output low voltage	$V_I = 2.7 \text{ V}$, $I_{O(\text{PG})} = 1 \text{ mA}$		0.15	0.4	V
	Leakage current	$V_{(\text{PG})} = 5 \text{ V}$			1	μA
Input current ($\overline{\text{EN}}$)		$\overline{\text{EN}} = 0 \text{ V}$	-1	0	1	μA
		$\overline{\text{EN}} = V_I$	-1		1	
Dropout voltage ⁽³⁾	TPS76628	$I_O = 250 \text{ mA}$, $T_J = +25^\circ\text{C}$		310		mV
		$I_O = 250 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			540	
	TPS76630	$I_O = 250 \text{ mA}$, $T_J = +25^\circ\text{C}$		270		
		$I_O = 250 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			470	
	TPS76633	$I_O = 250 \text{ mA}$, $T_J = +25^\circ\text{C}$		230		
		$I_O = 250 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			400	
	TPS76650	$I_O = 250 \text{ mA}$, $T_J = +25^\circ\text{C}$		140		
		$I_O = 250 \text{ mA}$, $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$			250	

(3) IN voltage equals $V_{O(\text{Typ})} - 100 \text{ mV}$; TPS76601 output voltage set to 3.3 V nominal with external resistor divider. TPS76615, TPS76618, TPS76625, and TPS76627 dropout voltage limited by input voltage range limitations (that is, TPS76630 input voltage must drop to 2.9 V for purpose of this test).



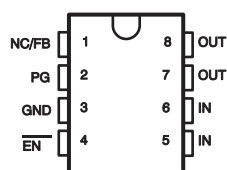
(1) See [Applications Information](#) section for capacitor selection details.

Figure 1. Typical Application Configuration for Fixed Output Options

FUNCTIONAL BLOCK DIAGRAM—ADJUSTABLE VERSION

TPS76615, TPS76618, TPS76625
TPS76627, TPS76628, TPS76630
TPS76633, TPS76650, TPS76601

D PACKAGE
SOIC-8
(TOP VIEW)



PIN DESCRIPTIONS

TPS766xx		I/O	DESCRIPTION
NAME	NO.		
EN	4	I	Enable input.
FB/NC	1	I	Feedback input voltage for adjustable device (not connected for fixed options).
GND	3		Regulator ground.
IN	5, 6	I	Input voltage.
OUT	7, 8	O	Regulated output voltage.
PG	2	O	Power good output.

Table 1. Table of Graphs

		FIGURE
Output voltage	vs Load current	Figure 2, Figure 3
	vs Free-air temperature	Figure 4, Figure 5
Ground current	vs Load current	Figure 6, Figure 7
	vs Free-air temperature	Figure 8, Figure 9
Power-supply ripple rejection	vs Frequency	Figure 10
Output spectral noise density	vs Frequency	Figure 11
Output impedance	vs Frequency	Figure 12
Dropout voltage	vs Free-air temperature	Figure 13, Figure 14
Line transient response		Figure 15, Figure 17
Load transient response		Figure 16, Figure 18
Output voltage	vs Time	Figure 19
Dropout voltage	vs Input voltage	Figure 20
Equivalent series resistance (ESR)	vs Output current	Figure 21 to Figure 24
Equivalent series resistance (ESR)	vs Added ceramic capacitance	Figure 25, Figure 26

TYPICAL CHARACTERISTICS

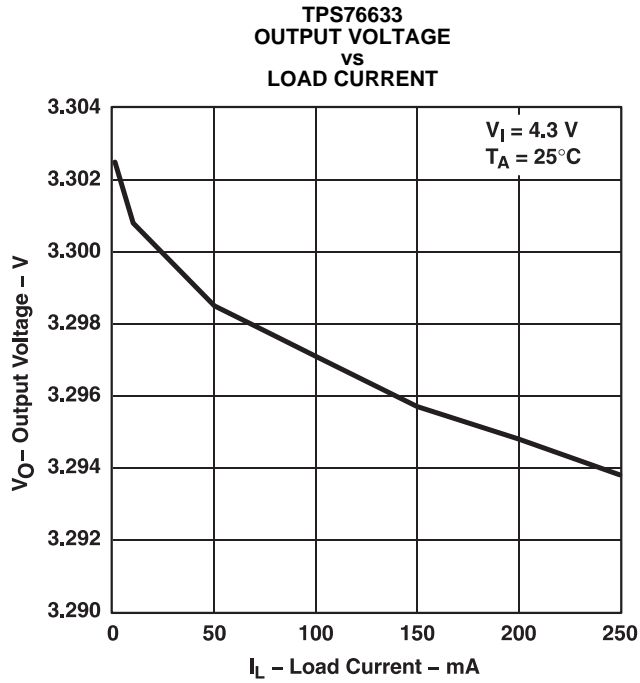


Figure 2.

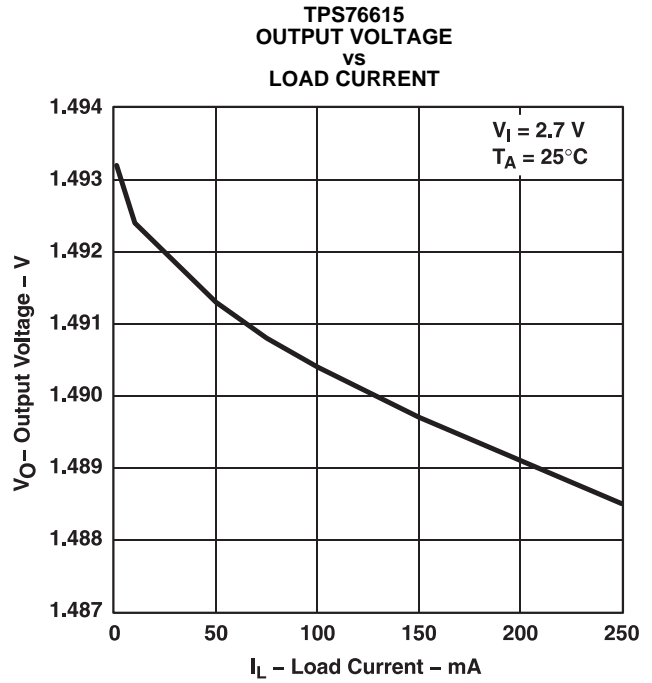


Figure 3.

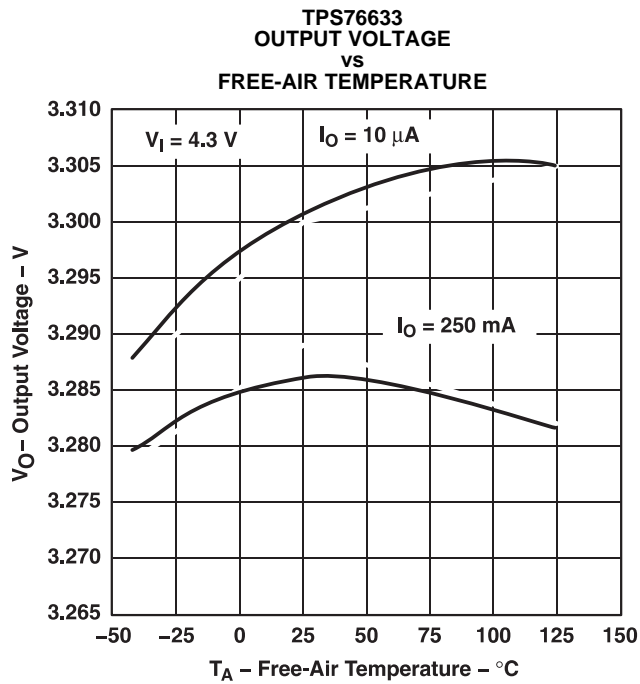


Figure 4.

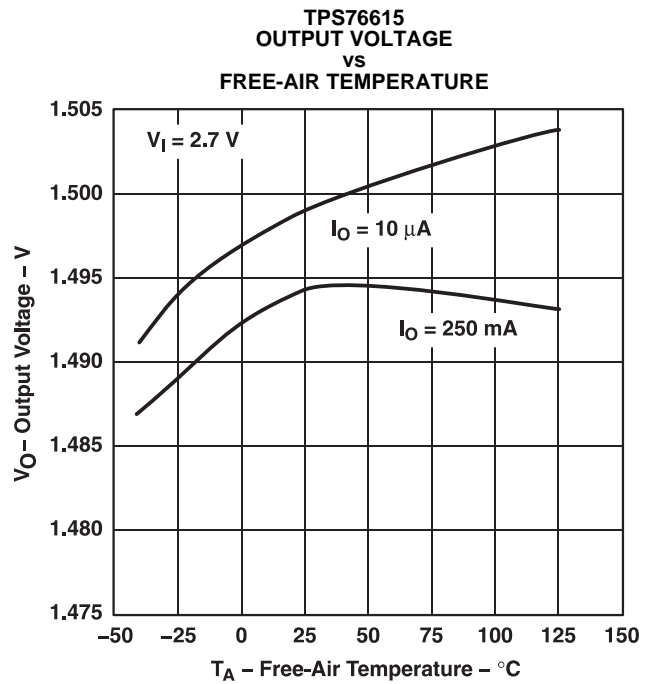


Figure 5.

TYPICAL CHARACTERISTICS (continued)

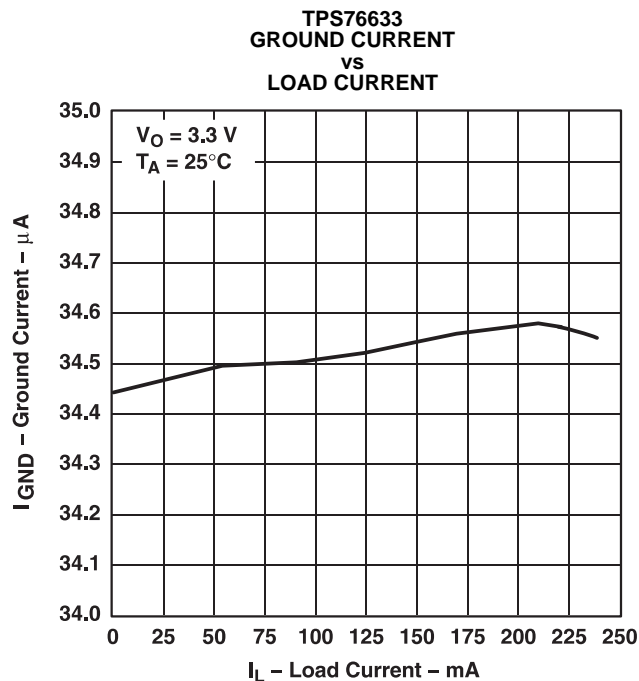


Figure 6.

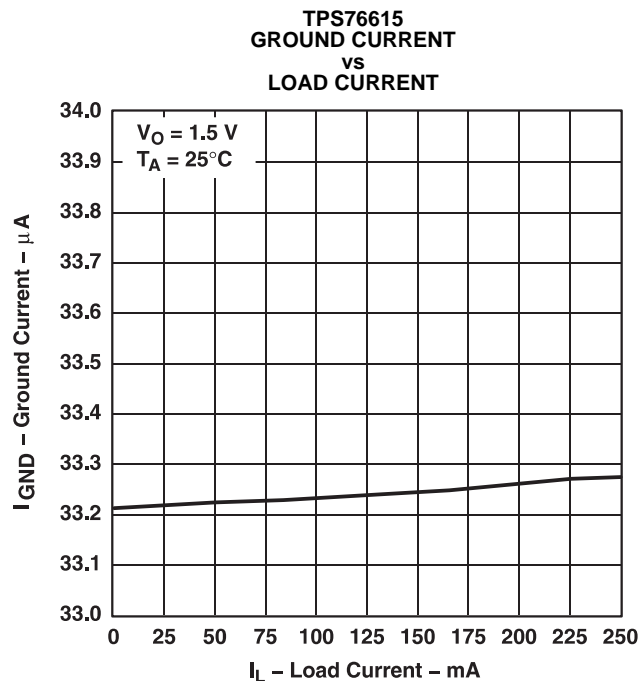


Figure 7.

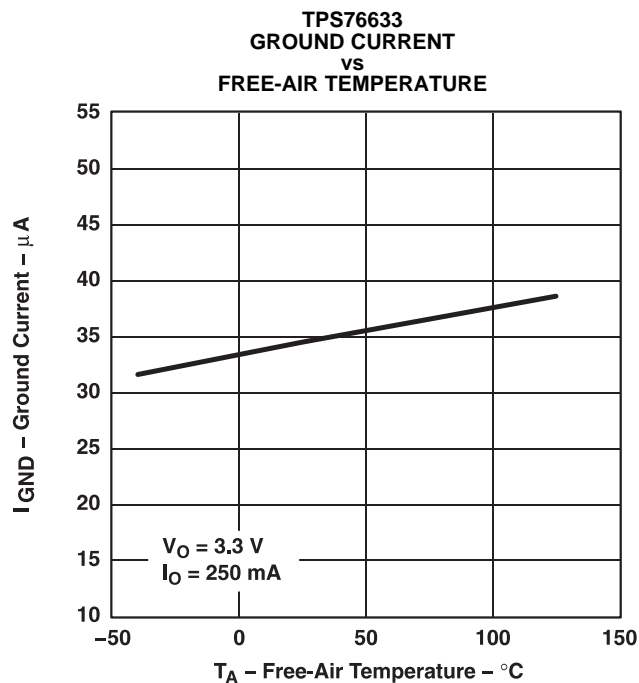


Figure 8.

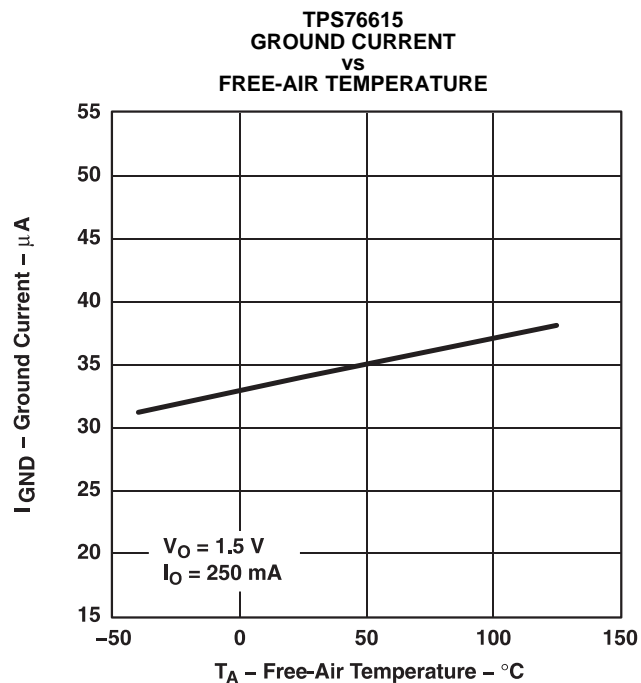


Figure 9.

TYPICAL CHARACTERISTICS (continued)

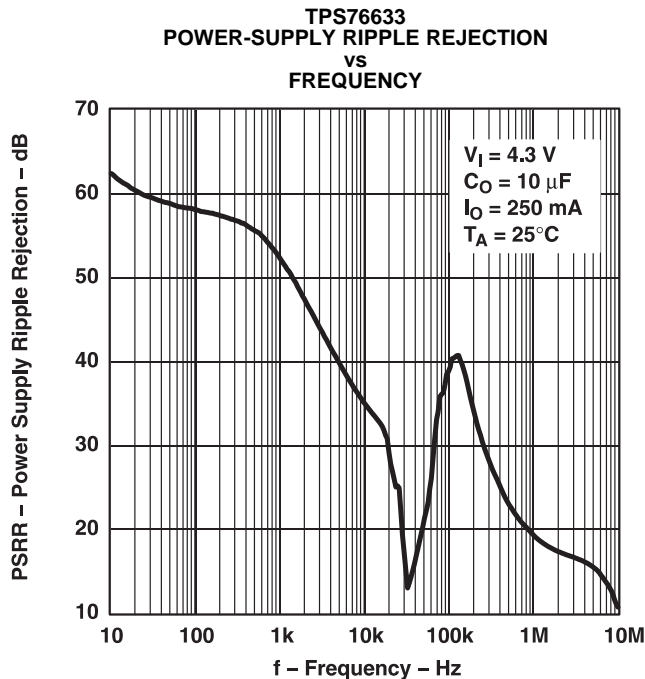


Figure 10.

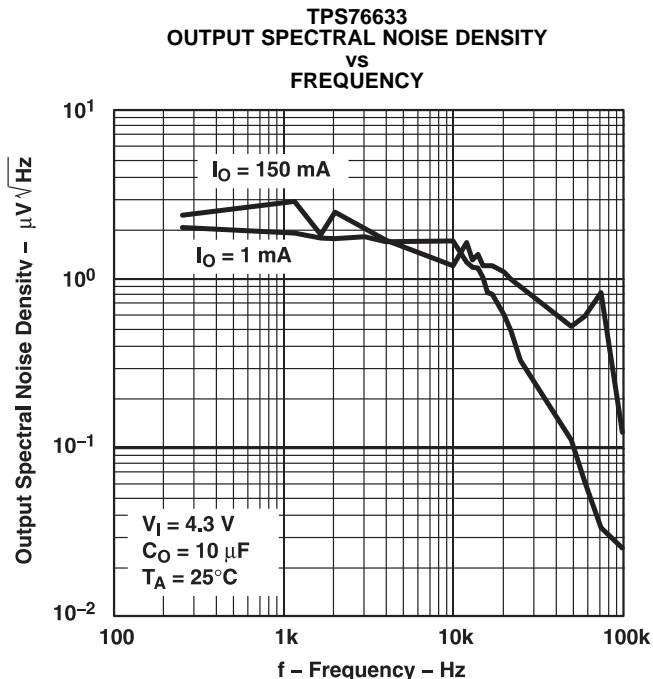


Figure 11.

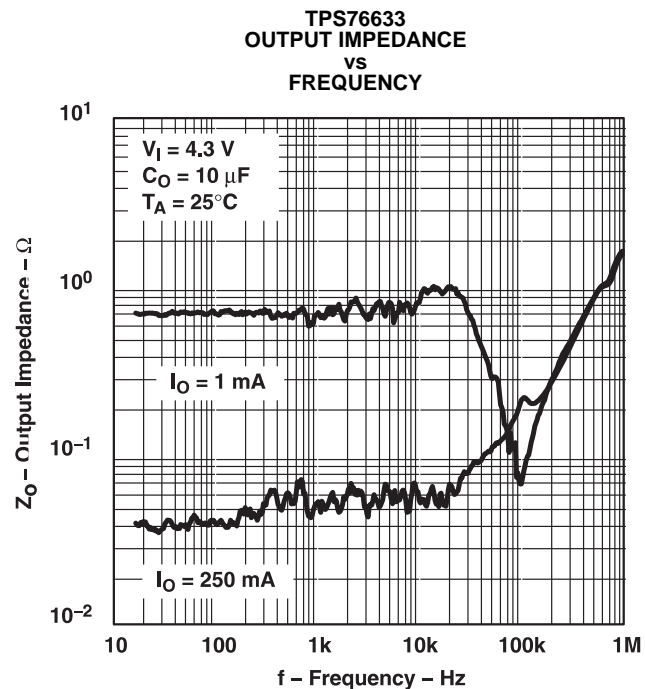


Figure 12.

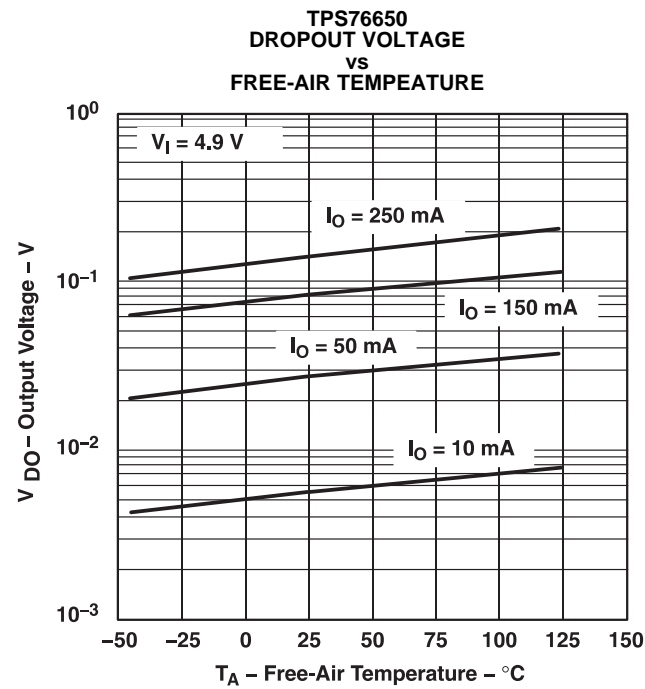


Figure 13.

TYPICAL CHARACTERISTICS (continued)

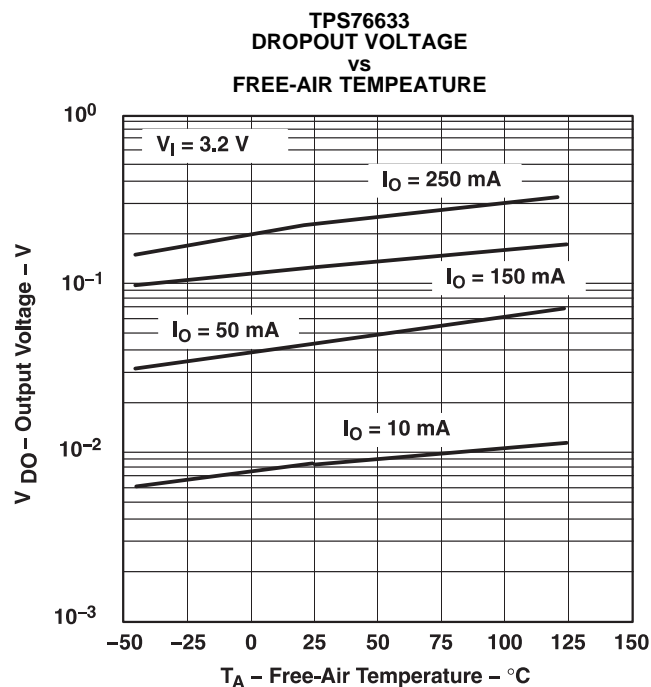


Figure 14.

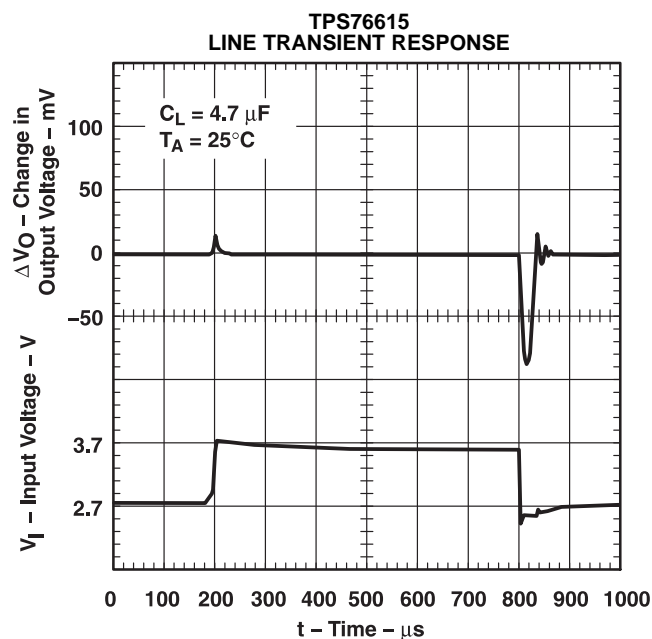


Figure 15.

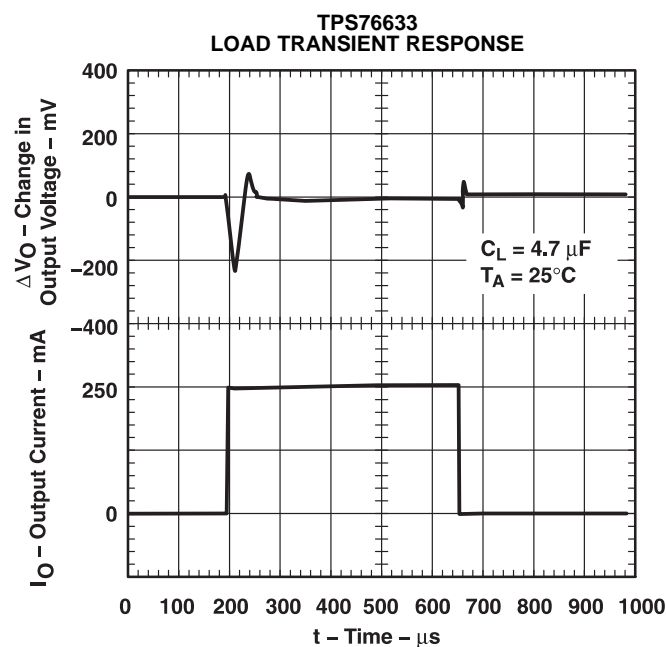


Figure 16.

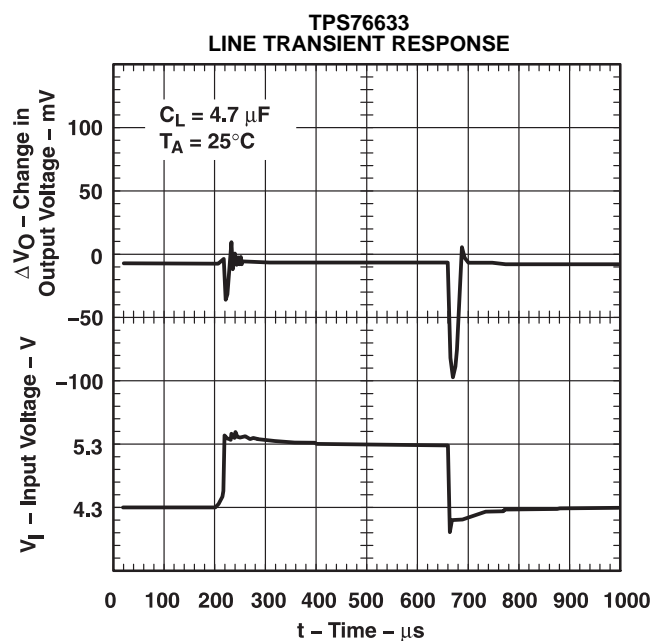


Figure 17.

TYPICAL CHARACTERISTICS (continued)

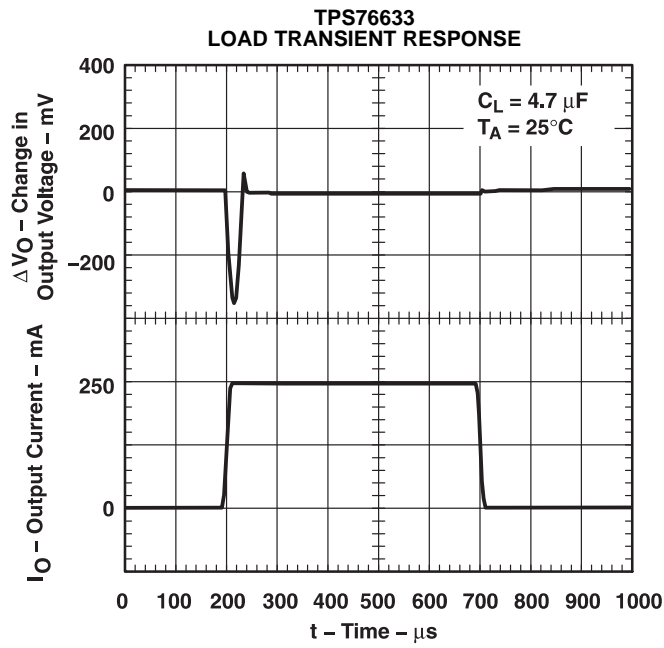


Figure 18.

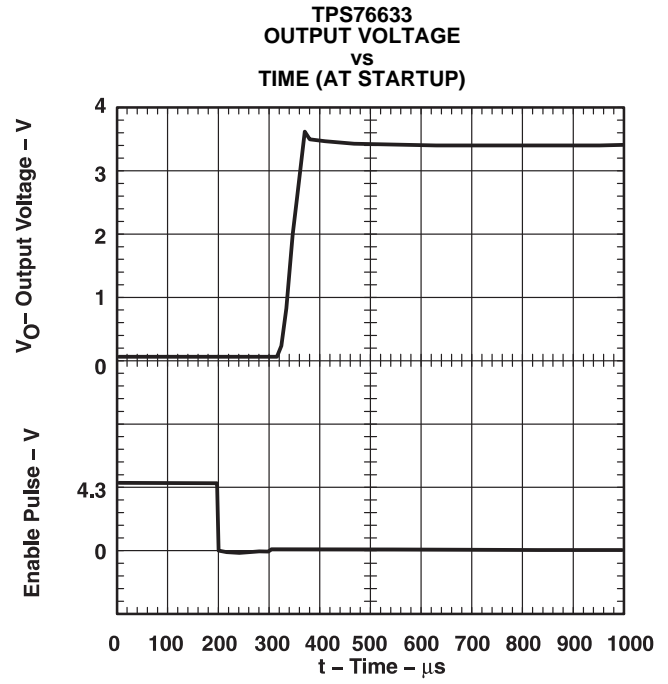


Figure 19.

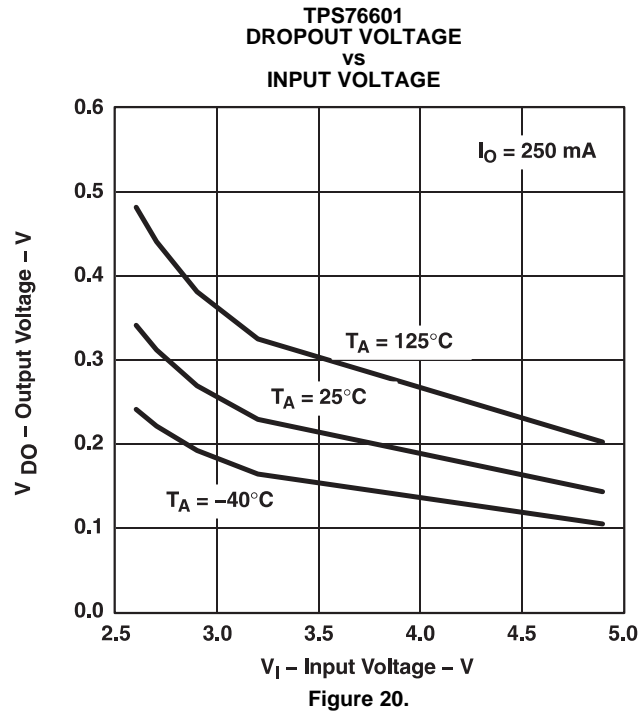


Figure 20.

TYPICAL CHARACTERISTICS (continued)

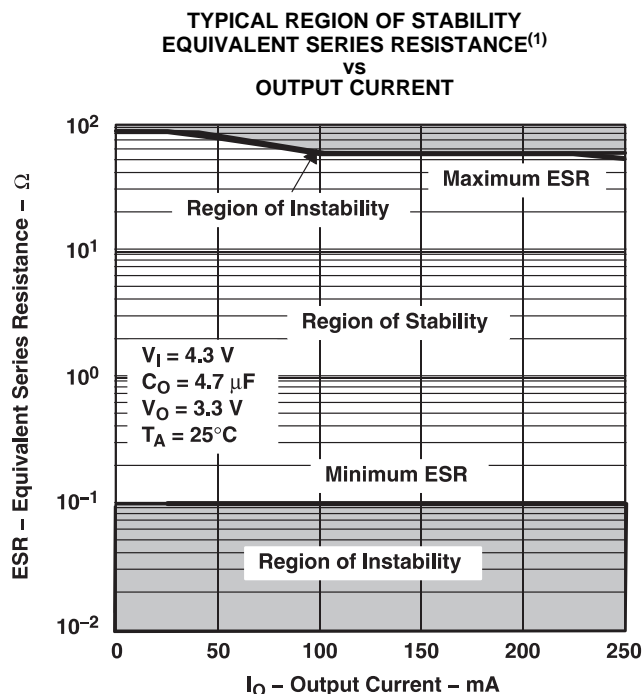


Figure 21.

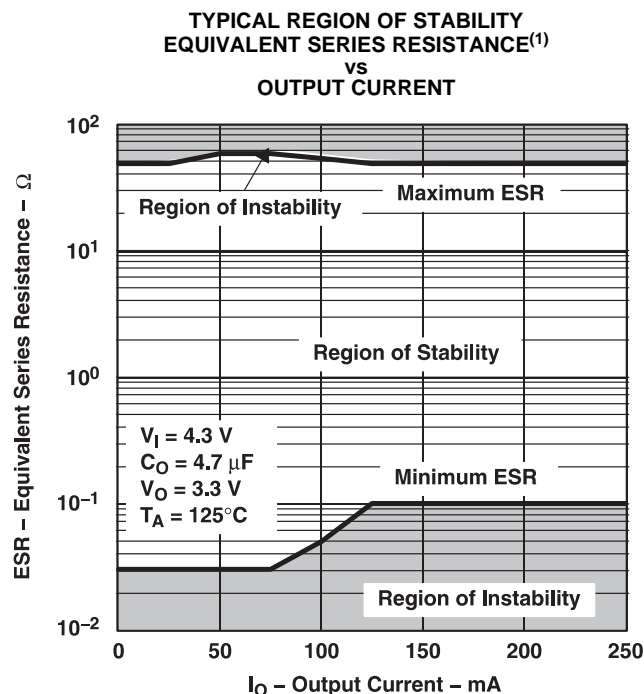


Figure 22.

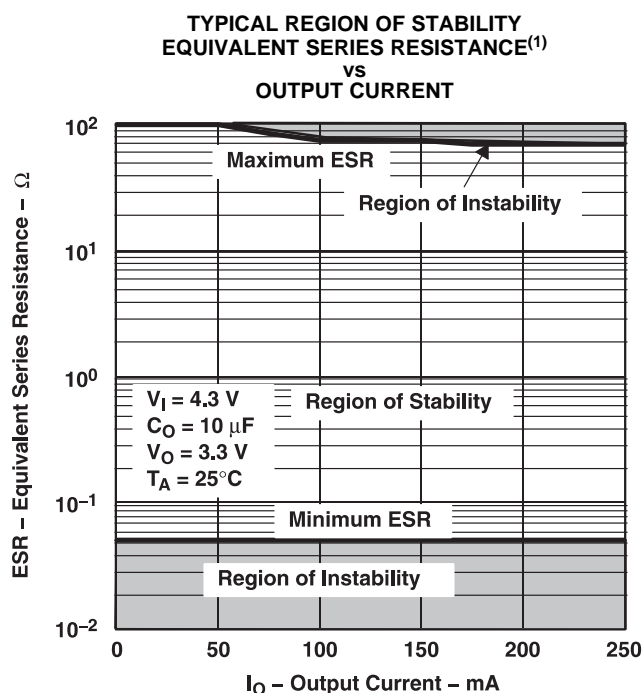


Figure 23.

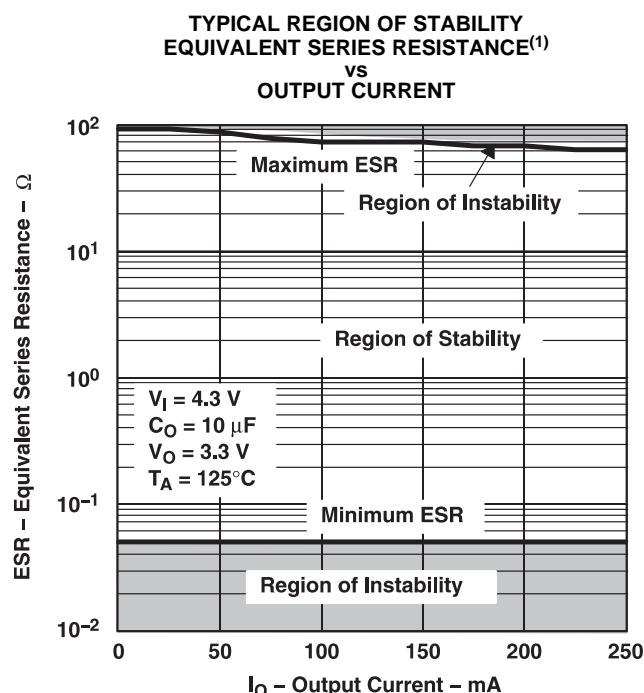


Figure 24.

⁽¹⁾ Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

TYPICAL CHARACTERISTICS (continued)

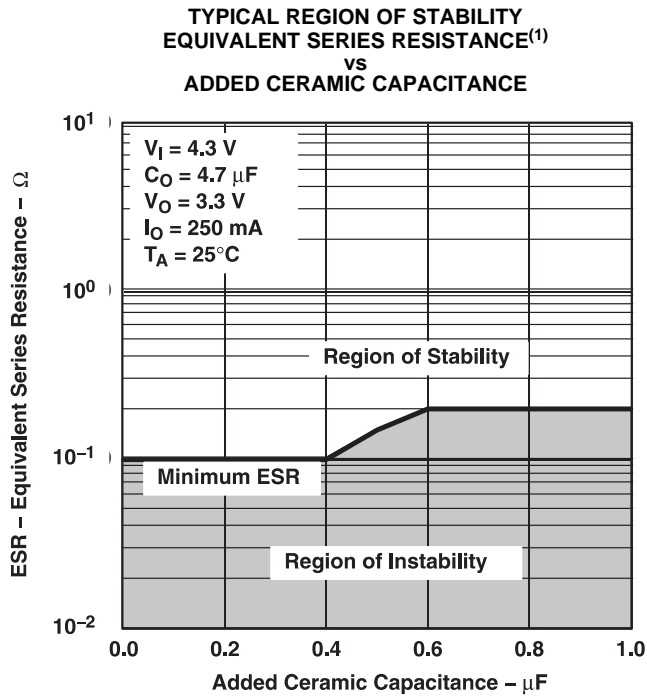


Figure 25.

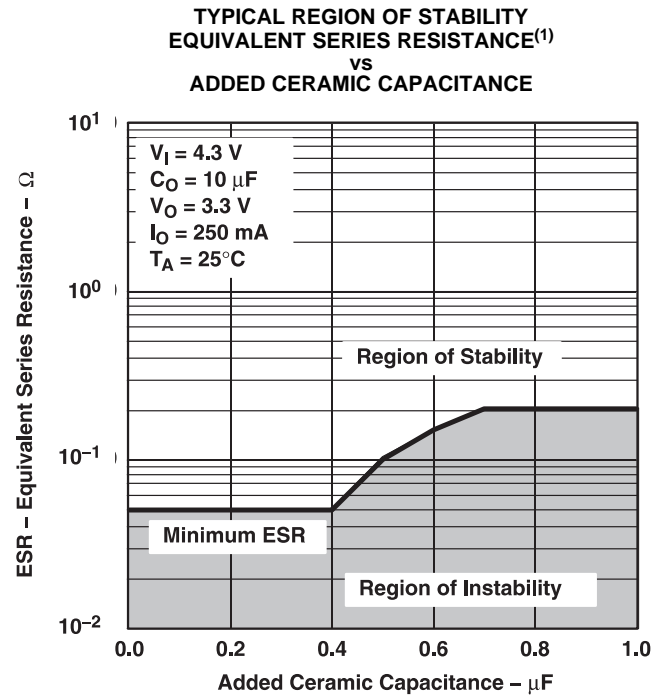


Figure 26.

⁽¹⁾ Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

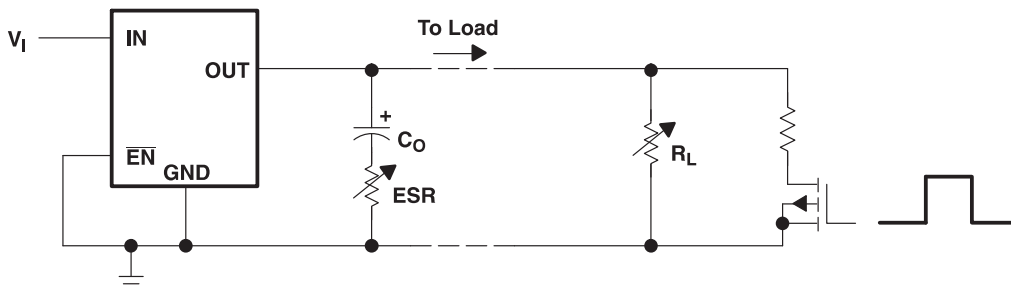


Figure 27. Test Circuit for Typical Regions of Stability (Figure 21 through Figure 24) (Fixed Output Options)

**TPS76615, TPS76618, TPS76625
TPS76627, TPS76628, TPS76630
TPS76633, TPS76650, TPS76601**

APPLICATION INFORMATION

The TPS766xx family includes eight fixed-output voltage regulators (1.5 V, 1.8 V, 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V, and 5.0 V), and an adjustable regulator, the TPS76601 (adjustable from 1.25 V to 5.5 V).

DEVICE OPERATION

The TPS766xx features very low quiescent current that remains virtually constant even with varying loads. Conventional LDO regulators use a pnp pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). The TPS766xx uses a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range.

Another pitfall associated with the pnp pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this increase in I_B translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS766xx quiescent current remains low even when the regulator drops out, eliminating both problems.

The TPS766xx family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to 1 μ A (typ). If the shutdown feature is not used, EN should be tied to ground. Response to an enable transition is quick; regulated output voltage is reestablished in typically 160 μ s.

MINIMUM LOAD REQUIREMENTS

The TPS766xx family is stable even at zero load; no minimum load is required for operation.

FB—PIN CONNECTION (ADJUSTABLE VERSION ONLY)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network to close the loop as shown in [Figure 29](#). Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance, wide-bandwidth amplifier and noise pickup feeds through to the regulator output. Routing the FB connection to minimize or avoid noise pickup is essential.

EXTERNAL CAPACITOR REQUIREMENTS

An input capacitor is not usually required; however, a ceramic bypass capacitor (0.047 μ F or larger) improves load transient response and noise rejection if the TPS766xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like most low dropout regulators, the TPS766xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 4.7 μ F and the ESR (equivalent series resistance) must be between 300 m Ω and 20 Ω . Capacitor values 4.7 μ F or larger are acceptable, provided the ESR is less than 20 Ω . Solid tantalum electrolytic and aluminum electrolytic capacitors are all suitable, provided they meet the requirements described previously. Ceramic capacitors, with series resistors that are sized to meet the previously described requirements, may also be used.

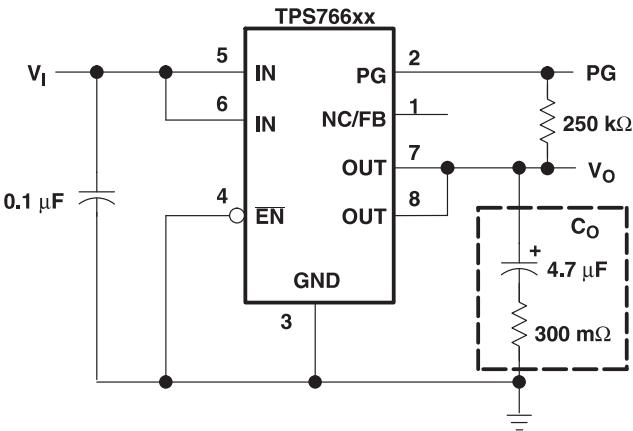


Figure 28. Typical Application Circuit (Fixed Versions)

PROGRAMMING THE TPS76601 ADJUSTABLE LDO REGULATOR

The output voltage of the TPS76601 adjustable regulator is programmed using an external resistor divider as shown in Figure 29. The output voltage is calculated using:

$$V_O = V_{ref} \times \left(1 + \frac{R1}{R2}\right)$$
 (1)

Where:

- $V_{ref} = 1.224 \text{ V typ}$ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 7-μA divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided because leakage currents at FB increase the output voltage error. The recommended design procedure is to choose $R2 = 169 \text{ k}\Omega$ to set the divider current at 7 μA, and then calculate R1 using:

$$R1 = \left(\frac{V_O}{V_{ref}} - 1\right) \times R2$$
 (2)

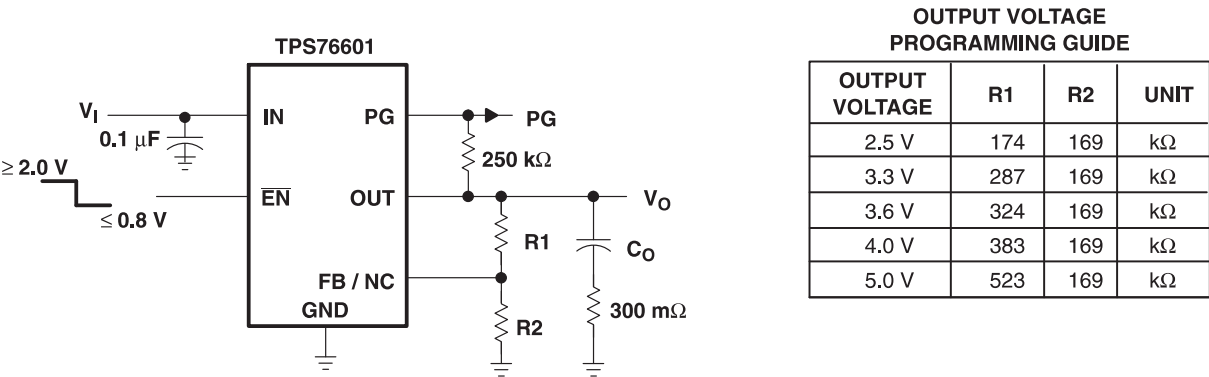


Figure 29. TPS76601 Adjustable LDO Regulator Programming

TPS76615, TPS76618, TPS76625
TPS76627, TPS76628, TPS76630
TPS76633, TPS76650, TPS76601

POWER-GOOD INDICATOR

The TPS766xx features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or used as a low-battery indicator.

REGULATOR PROTECTION

The TPS766xx PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (for example, during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS766xx also features internal current limiting and thermal protection. During normal operation, the TPS766xx limits output current to approximately 0.8 A (typ). When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds +150°C (typ), thermal-protection circuitry shuts it down. Once the device has cooled below +130°C (typ), regulator operation resumes.

POWER DISSIPATION AND JUNCTION TEMPERATURE

Specified regulator operation is assured to a junction temperature of +125°C; the maximum junction temperature should be restricted to +125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{Jmax} - T_A}{R_{\theta JA}} \quad (3)$$

Where:

- T_{Jmax} is the maximum allowable junction temperature;
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package (that is, 176°C/W for the 8-terminal SOIC); and
- T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O \quad (4)$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation triggers the thermal protection circuit.

PACKAGE OPTION ADDENDUM

15-Apr-2017

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS76601D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76601	Samples
TPS76601DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76601	Samples
TPS76601DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76601	Samples
TPS76615D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76615	Samples
TPS76615DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76615	Samples
TPS76615DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76615	Samples
TPS76615DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76615	Samples
TPS76618D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76618	Samples
TPS76618DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76618	Samples
TPS76618DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76618	Samples
TPS76618DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76618	Samples
TPS76625D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76625	Samples
TPS76625DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76625	Samples
TPS76625DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76625	Samples
TPS76625DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76625	Samples
TPS76628D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76628	Samples
TPS76628DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76628	Samples

PACKAGE OPTION ADDENDUM

15-Apr-2017

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS76630D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76630	Samples
TPS76630DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76630	Samples
TPS76633D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76633	Samples
TPS76633DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76633	Samples
TPS76633DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76633	Samples
TPS76633DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76633	Samples
TPS76650D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76650	Samples
TPS76650DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76650	Samples
TPS76650DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		76650	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

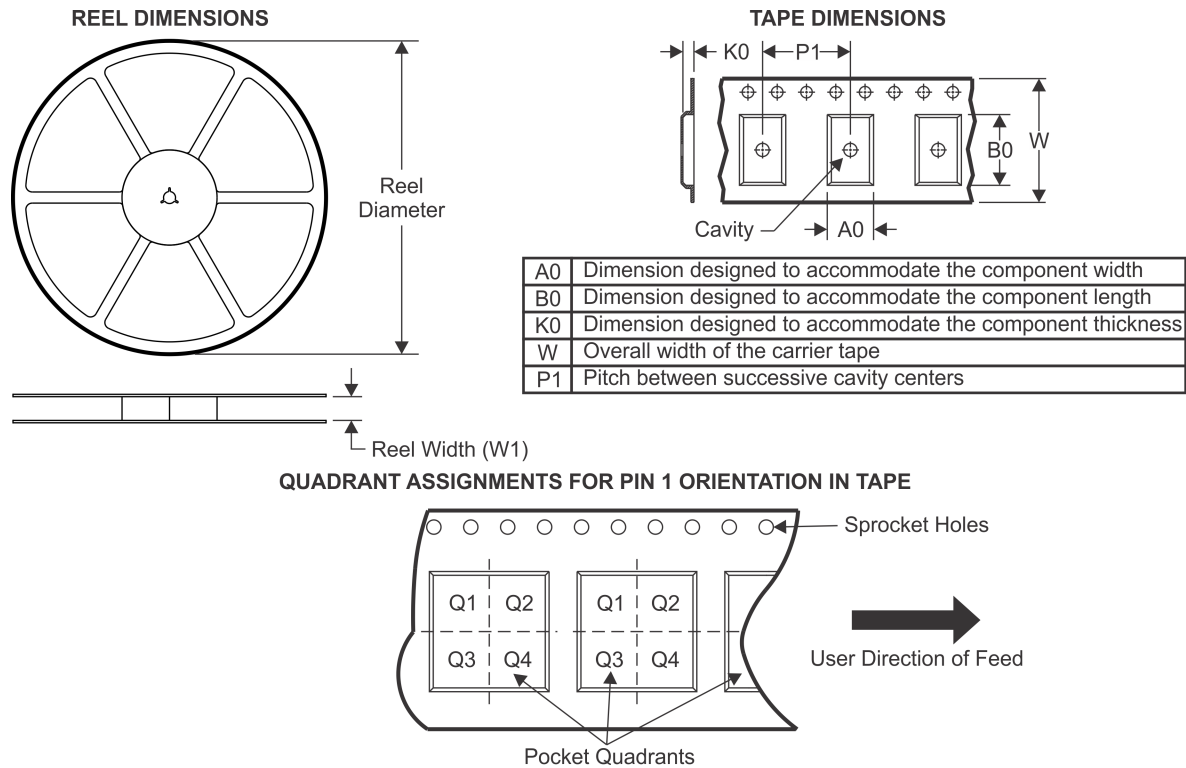
⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION



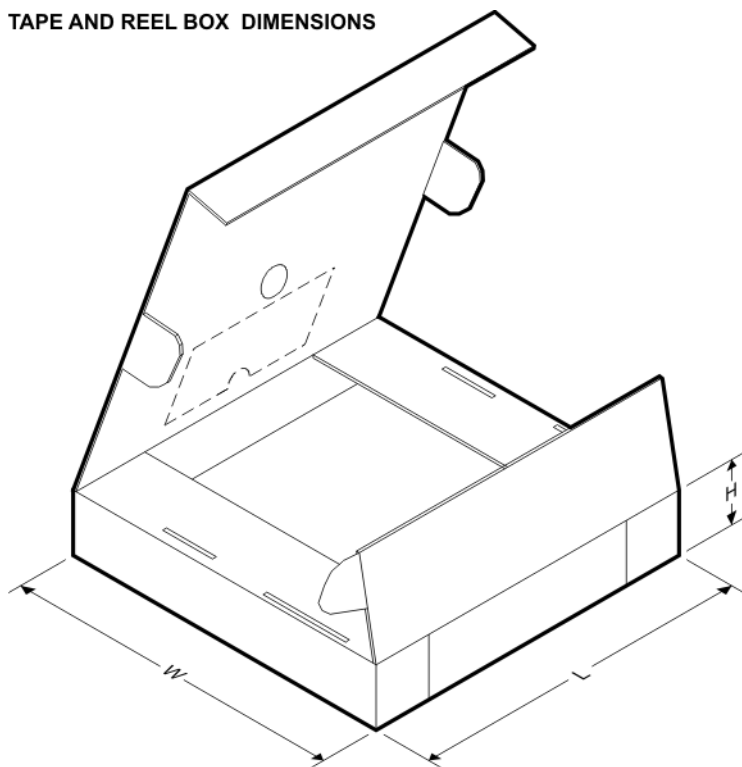
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS76601DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76615DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76618DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76625DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76628DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76633DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76633DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76650DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

13-Feb-2016

TAPE AND REEL BOX DIMENSIONS

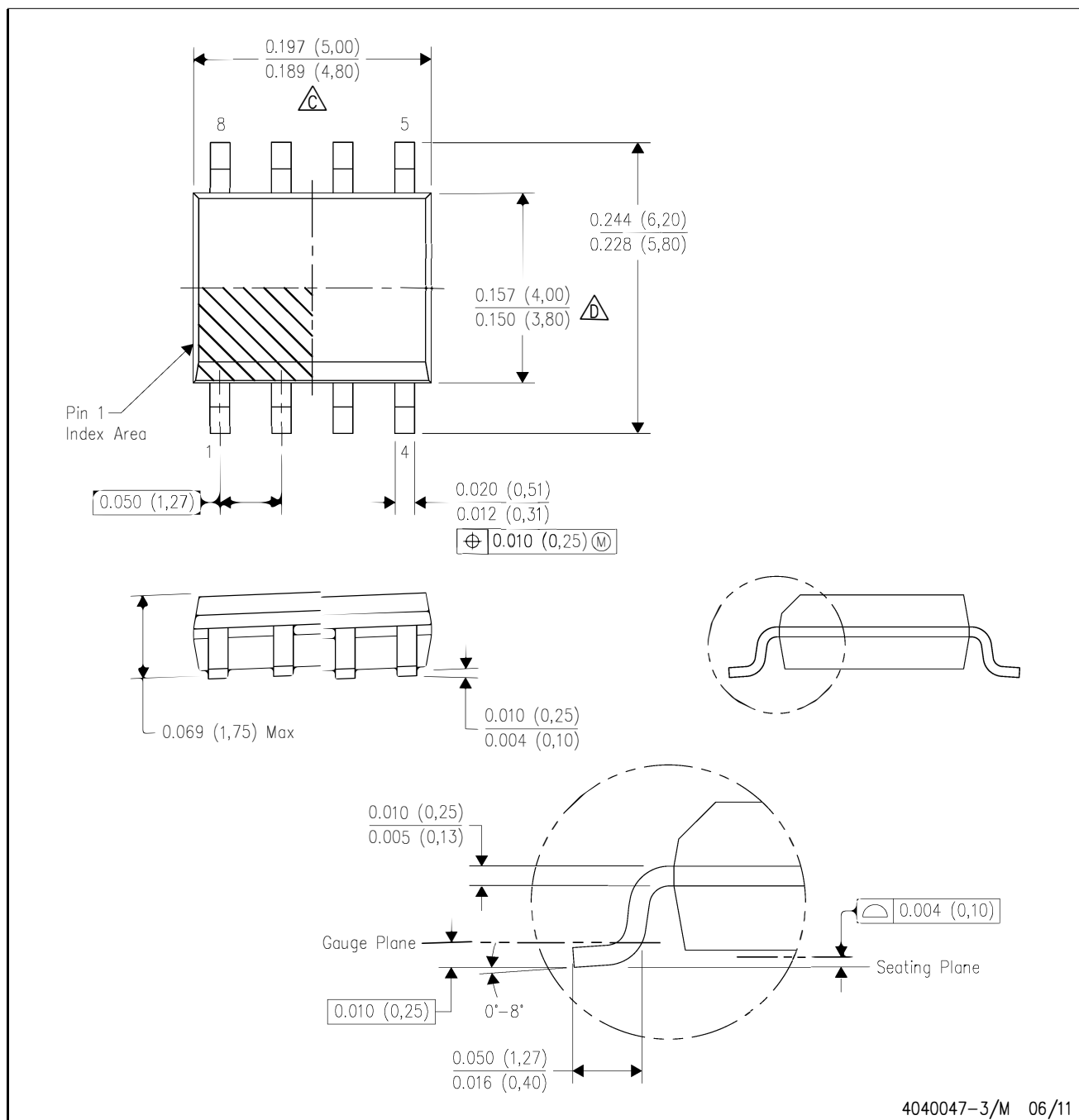


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS76601DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76615DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76618DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76625DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76628DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76633DR	SOIC	D	8	2500	367.0	367.0	38.0
TPS76633DR	SOIC	D	8	2500	367.0	367.0	35.0
TPS76650DR	SOIC	D	8	2500	367.0	367.0	38.0

D (R-PDSO-G8)

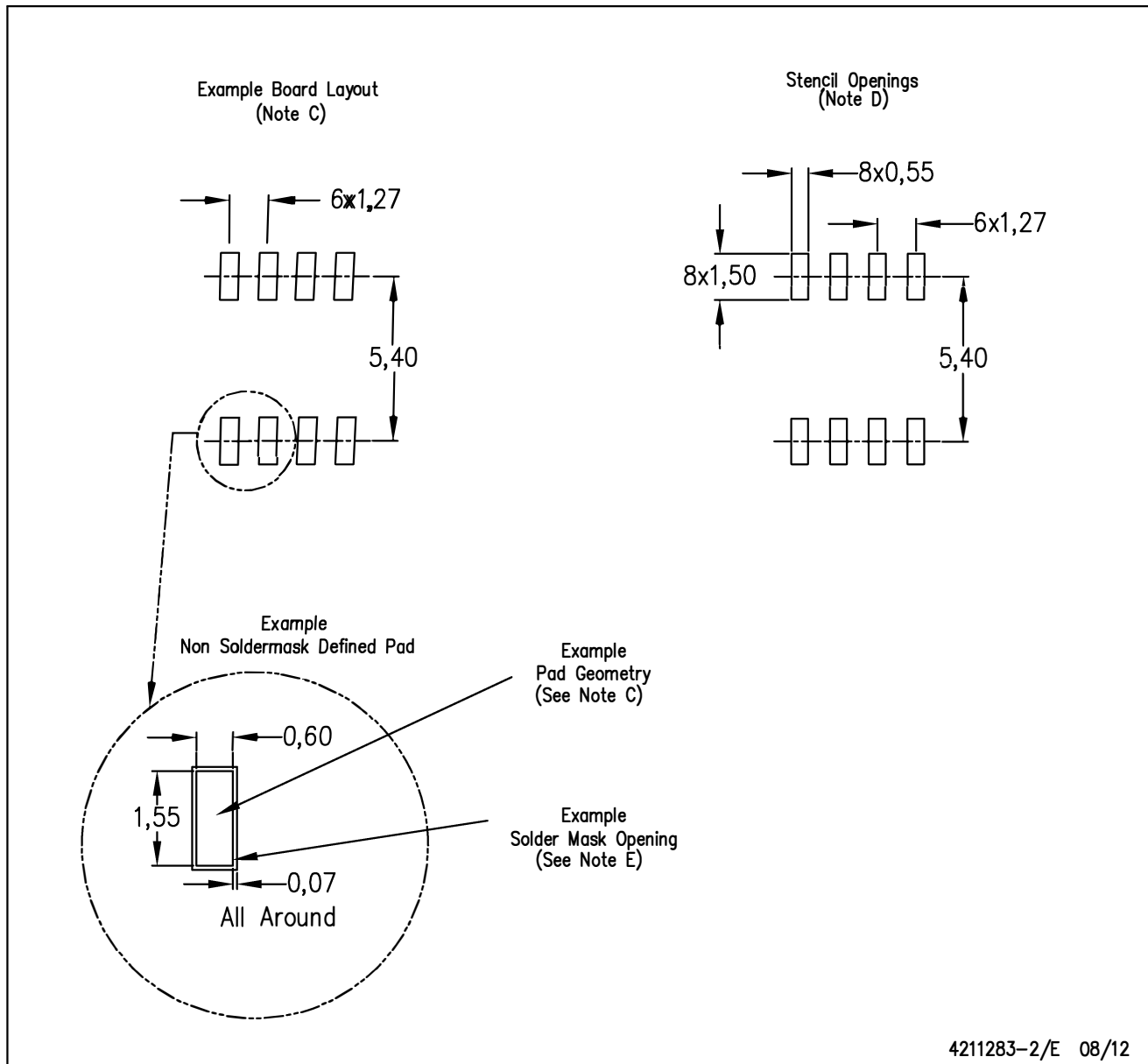
PLASTIC SMALL OUTLINE



4040047-3/M 06/11

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.